

ZN508

DUAL 8-BIT MICROPROCESSOR COMPATIBLE D-A CONVERTER

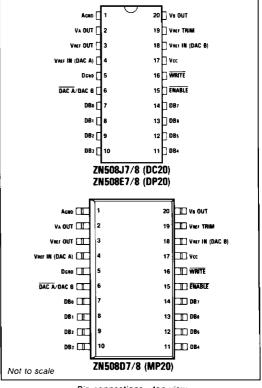
The ZN508 is a monolithic dual 8-bit DAC designed to be easily interfaced to microprocessors. Integrated on-chip are two 8-bit DAC's, a 2.5V trimmable bandgap reference, separate VREF inputs and data latches for each DAC. The on-chip reference not only can be used to drive the two DAC's but can be also used as a system reference. A consequence of the two DAC's being fabricated on the same chip is excellent, inherent, DAC to DAC matching.

FEATURES

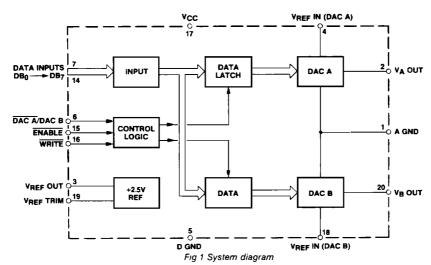
- 800ns Voltge Settling Time
- 2 5V Trimmable Bandgap Reference
- Monotonic over Full Temperature Range
- Single +5V Supply
- Excellent DAC to DAC Matching
- Separate VREF IN for each DAC
- Commercial and Military Temperature Ranges

ORDERING INFORMATION

Device type	Linearity error (LSB)	Operating temperature	Package
ZN508E7	±1	-40°C to +85°C	DP20
ZN508E8	±½	-40°C to +85°C	DP20
ZN508D7	±1	-40°C to +85°C	MP20
ZN508D8	±1/2	-40°C to +85°C	MP20
ZN508J7	±1	-55°C to +125°C	DC20
ZN508J8	±1/2	-55°C to +125°C	DC20



Pin connections - top view



ABSOLUTE MAXIMUM RATINGS

Supply voltage Vcc Max. voltage, logic and VREF input Operating temperture range ZN508E and ZN508D

+Vcc-40°C to +85°C

+7V

ZN508J Storage temperature range Analog ground to digital ground -55°C to 125°C -55°C to 125°C ±200mV

ELECTRICAL CHARACTERISTICS

Test conditions (unless otherwise stated): $T_{amb} = 25 \,^{\circ}\text{C}$

	Value					
Characteristic	Min. Typ. Max.		Max.	Units	Conditions	
ZN508-8	 		 	 		
Linearity error			±0.5	LSB		
Differential linearity error			±0.75	LSB		
ZN508-7						
Linearity error			±1.0	LSB		
Differential linearity error			±1.0	LSB		
All types						
Linearity error TC		±3		ppm/°C		
Differential non-linearity TC		±6		ppm/°C		
·		2	_	mV	All bits OFF	
Offset voltage ZN508E ZN508D		2	5	mV	All bits OFF	
ZN508J		2	5	mV	All bits OFF	
		1	ا	1	All Diffs Of 1.	
Offset voltage TC		±3		ppm/°C	[,	
Full scale output	2.545	2.550	2.555	V	External reference	
				ł	VREF IN = 2.560V,	
Full scale output TC		2		ppm/°C	all bits ON	
Analog output resistance		4		kΩ		
External reference voltage	0		3.0	V		
Settling time to 0.5 LSB		800		ns	1 LSB major transition (Note 1)	
		1.25		μs	All bits ON to OFF or OFF to ON (Note 1)	
Supply voltage (Vcc)	4.5	5.0	5.5	l v		
Supply current		36		mA		
Power consumption		180		mW		
DC supply rejection		-57		dB	ΔVcc = 250μV p-p f ≤ 50kHz	
Digital to analog glitch impulse				2//2		
Digital to analog glitch impulse				nV-s	00000000 11111111	
Channel to channel isolation						
VREF A to Out B		-82		dB	} f ≤ 50kHz	
VAEF B to Out A		-82		dB	'	
Internal voltage reference		1				
Output voltage		2.5		V		
Slope impedance		1		Ω		
VAEF OUT TC		50		ppm/°C		
Reference current	1		15	mA		
Logic						
(over specified operating temperature range)						
High level input voltage V⊩	2.0			V		
Low level input voltage Vil.			0.8	V		
High level input current Іін			20	μΑ	$V_{IN} = 2.4, V_{CC} = 5.5V$	
			320	μA	$V_{IN} = 5.5, V_{CC} = 5.5V$	
Low level input current lic			-310	μA	Vin = 0.4V, Vcc = 5.5V	

Characteristic		Value			
Characteristic	Min.	Тур.	Max.	Units	Conditions
Switching characteristics					
Chip select to write set up time tos	150			ns	
Chip select to write hold time, Tch	10			ns	
DAC select to write set up time tas	150			ns	
DAC select to write hold time tah	10			ns	
Data valid to write set up time tos	100			ns	
Data valid to write hold time ton	50			ns	
Write pulse width twe	150			ns	

NOTE

1. Rt = 10 Megohms Ct = 10pF

D-A CONVERTER

The converters are of the voltage switching type and use an R-2R ladder network as shown in Fig.2. Each 2R element is connected to 0V or VREF IN by transistor voltage switches specially designed for low offset voltage (<1mV). A binary weighted voltage is produced at the output of the R-2R ladder.

Analog output
$$=\frac{n}{256} (V_{REF} IN - V_{OS}) + V_{OS}$$

where n is the digital input to the D-A from the data latch.

Vos is a small offset voltage produced by the D-A switch currents flowing through the package lead resistance. The value of Vos is typically 1mV. This offset will normally be removed by the setting up procedure (see Operating Notes) and because the offset temperature coefficient is low $(\pm 6\mu V/^{\circ}C)$ the effect on accuracy is negligible.

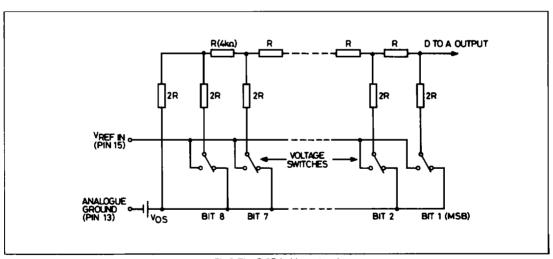


Fig.2 The R-2R ladder network

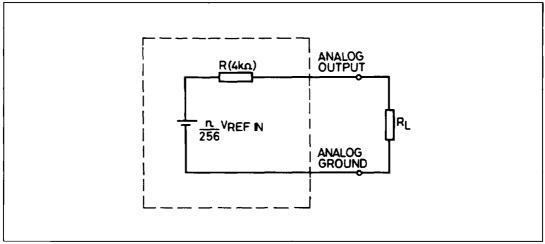


Fig.3 Analog output equivalent circuit

Fig 3 shows an equivalent circuit of the outputs (ignoring Vos). The output resistance R has a temperature coefficient of ±0.2% per °C.

The gain drift due to this is
$$0.2R$$
 % per °C $R + R$

RL should be chosen to be as large as possible to make the gain drift small. As an example if RL = 400k Ω then the gain drift due to the TC of R for a 100°C change in ambient temperature will be less than 0.2%. Alternatively the ZN508 outputs can be buffered by amplifiers (see Operating Notes)

REFERENCE

1. Internal Reference

The internal reference is an active band gap circuit which is equivalent to a 2.5V Zener diode with a very low slope impedance (Fig 3). A resistor (RREF), should be connected between $\pm V_{\rm CC}$ (pin 11) and pin 15. The recommended value of 1.5k will supply a nominal reference current of (5-2.5)/1500 = 1.7mA.

The reference voltage can be trimmed by $\pm 5\%$ with a 10k potentiometer (as shown in Fig 5).

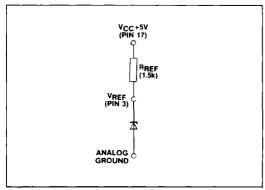


Fig 4 Internal voltage reference

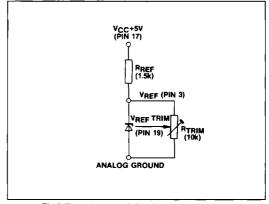


Fig 5 Trimming circuit for the voltage reference

2. External Reference

If required an external reference voltage may be connected to VREF IN. The slope resistance of such a reference source should be less than 2.5Ω , where n is the

number of converters supplied

 $\mbox{V}_{\mbox{\scriptsize REF}}$ IN can be varied from 0 to $\pm 3\mbox{V}$ for ratiometric operation. The ZN508 is guaranteed monotonic for $\mbox{\scriptsize V}_{\mbox{\scriptsize REF}}$ IN above 2V.

LOGIC

Input coding is binary for unipolar operation and offset binary for bipolar operation Both DAC A and DAC B share an internal data bus and an 8-bit input port. The DAC to be loaded with new data is chosen by DAC A/DAC B select pin. DAC A when the input is low and DAC B when the input is high. When ENABLE and WRITE are both low the DAC selected is in the write mode. The input data latches of the selected DAC are transparent and its analog output responds to the data presented to the input port. The data is then latched when either ENABLE or WRITE are taken high

DAC A/DAC B	ĊS	WR	DAC A	DAC B
L	L	L	WRITE	HOLD
Н	L	L	HOLD	WRITE
X	н	×	HOLD	HOLD
×	×	н	HOLD	HOLD

Table 1 Logic truth table

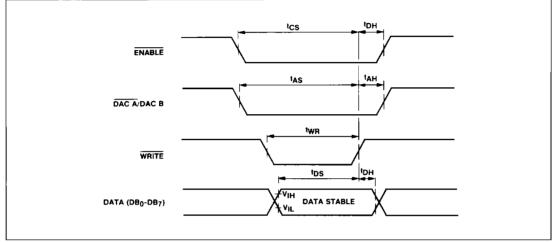


Fig.6 Logic timing diagram

OPERATING NOTES

In some applications the standard 0 to VREF IN output voltage range and drive capability are not suitable, and other output ranges, both unipolar and bipolar are required.

To maintain flexibility two types of operational amplifier are illustrated: the industry standard 741 and a low cost pincompatible alternative with a JFET input, the LF351. The LF351 features a high slew rate of $13V/\mu s$, which gives a faster potential settling time than the 741. To keep drift to a minimum when using the 741, the external range setting resistors are calculated to match them to the $4k\Omega$ ladder output impedance. This is not a consideration with the LF351, as the input offset current change with temperature is negligible for the impedances concerned. The resistor values for the LF351 were chosen to keep the output ringing to a minimum, a problem sometimes encountered with high slew rate op-amps. It is only the relative and not the absolute values of these resistors which set the range, and therefore can be changed as long as their ratios remain the same.

Unipolar Operation

The general scheme for unipolar operation is shown in Fig 6 and is suitable for amplifiers with input bias currents less than $1.5\mu A$

The resulting full scale range is given by

Vout FS =
$$1 + \frac{R1}{R2}$$
 (Vaer IN - 1 LSB)
= G (Vaer IN) - 1 LSB)

The impedance at the inverting input is R1/R2 and for low drift with temperature (741 only), this parallel combination should be equal to the ladder resistance ($4k\Omega$).

The required nominal values of R1 and R2 are therefore given by R1 $\,=\,$ 4Gk Ω and R2 $\,=\,$ 4G/(G-1)k Ω

Using these relationships a table of nominal resistance values for R1 and R2 can be constructed for Ver IN = 2.5V (Table 2) For gain setting R1 is adjusted about its nominal value. Practical circuit realisations for +5V and +10V output ranges are given in Figs 8 and 9

Output range	G	R1	R2
+ 5V	2	8kΩ	8kΩ
+ 10V		16kΩ	5 33kΩ

Table 2 Nominal values for R1 and R2

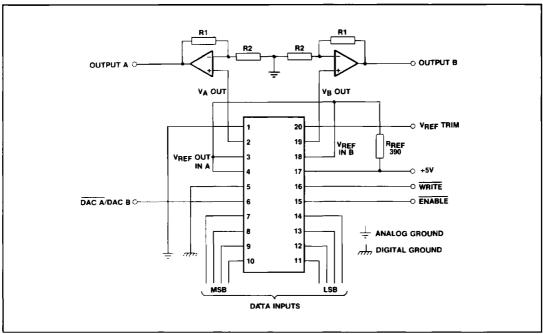


Fig.7 Unipolar operation - basic circuit

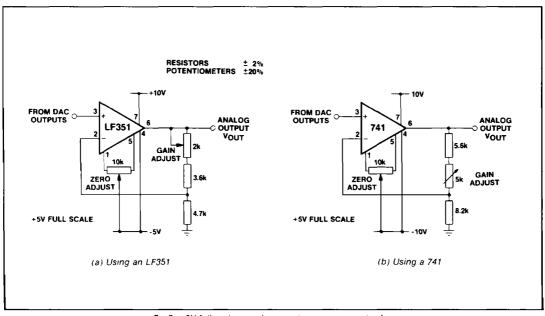


Fig 8 +5V full scale unipolar operation - component values

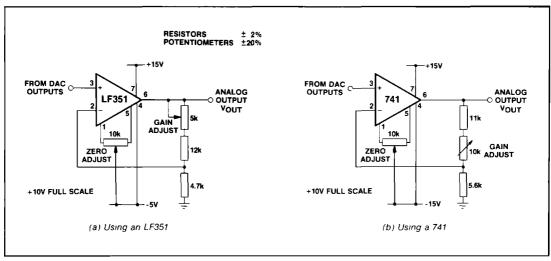


Fig.9 +10V full scale unipolar operation - component values

Unipolar Adjustment Procedure

- 1 Set all bits to OFF (low) with $\overline{\text{ENABLE}}$ low and adjust zero until Vout = 0.0000V
- 2 Set all bit ON (high) and adjust gain until $V_{OUT} = FS 1$ LSB.

Output range, +FS	LSB	FS - 1 LSB	
+ 5V	19.5mV	4 9805V	1 LSB = FS
+10V	39.1mV	9.9609V	256

Table 3 Unipolar setting up points

Input code (Binary)	Analog output (nominal value)
11111111	FS - 1 LSB
11111110	FS - 2 LSB
11000000	¾ FS
10000001	1/2 FS + 1 LSB
10000000	½ FS
01111111	½ FS - 1 LSB
01000000	14 FS
00000001	1 LSB
00000000	0

Table 4 Unipolar logic coding

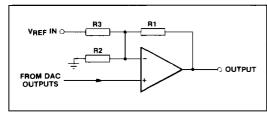


Fig.10 Bipolar operation

Bipolar Operation

For bipolar operation the output from the ZN508 is offset by half full scale by connecting a resistor R3 between VREF IN and the inverting input of the buffer amplifier (Fig.10)

When the digital input to the ZN508 is zero the analog output is zero and the amplifier output should be – full scale. An input of all ones to the D-A will give a ZN508 output of VREF IN – 1 LSB and an amplifier output of \pm full scale. When using the 741, the parallel combination of R1, R2 and R3 should match the $4k\Omega$ ladder resistance

The nominal values of R1, R2 and R3 which meet these conditions are given by

R1 = 8Gk
$$\Omega$$
, R2 = 8G/(G-1)k Ω and R3 = 8k Ω .

where the resultant output range is $\pm G V_{REF} IN$.

A binary output range of $\pm V_{\text{REF}}$ IN (which corresponds to the basic unipolar range 0 to V_{\text{REF}} IN) is obtained if R1 = R3 = 8k Ω and R2 = ∞

Assuming that VREF IN = 2.5V the nominal values of resistors for \pm 5V and \pm 10V output ranges are given in Table 5

Output range	G	R1	R2	R3
+ 5V	2	16kΩ	16kΩ	8kΩ
± 10V		32kΩ	10 66kΩ	8kΩ

Table 5

Minus full scale (offset) is set by adjusting R1 about its nominal value relative to R3. Plus full scale (gain) is set by adjusting R2 relative to R1.

Practical circuit realisations are given in Figs. 11 and 12. Note that in the $\pm 5V$ case (741 only), R3 has been chosen as $7.5k\Omega$ (instead of $8.2k\Omega$) to give a more symmetrical range of adjustment using standard potentiometers

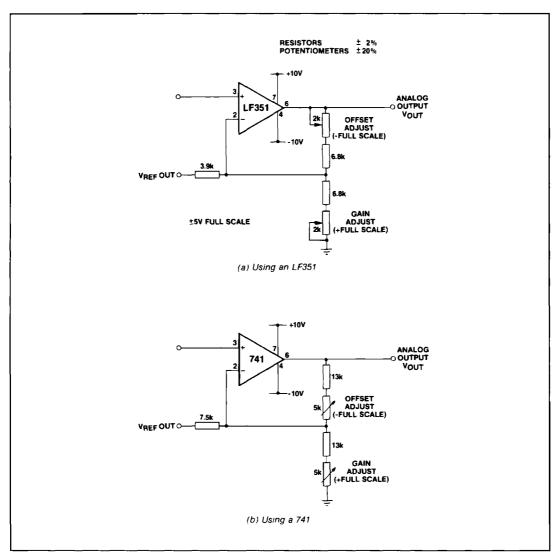


Fig. 11 ±5V full scale bipolar operation - component values

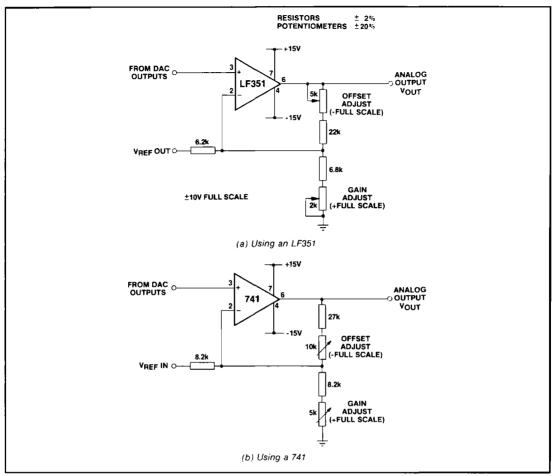


Fig.12 \pm 10V full scale bipolar operation - component values

Bipolar Adjustment Procedure

1 Set all bits to OFF (low) with ENABLE low and adjust offset until the amplifier output reads - full scale

2. Set all bits ON (high) and adjust gain until the amplifier output reads \pm (full scale \pm 1 LSB)

Input range, \pm FS	LSB	-FS	+(FS - 1 LSB)	
±5V	39.1mV	-5.0000V	+4.9609V	11
±10V	78.1mV	-10 0000V	+9.9219V	

 $1 LSB = \frac{2FS}{256}$

Table 6 Bipolar setting up points

Input code (offset binary)	Analog output (nominal value)
11111111	+(FS - 1 LSB)
11111110	+(FS - 2 LSB)
11000000	+1/2 FS
10000001	+1 LSB
10000000	0
01111111	-1 LSB
01000000	-½ FS
00000001	-(FS - 1 LSB)
00000000	-FS

Table 7 Bipolar logic coding